UNISONIC TECHNOLOGIES CO., LTD

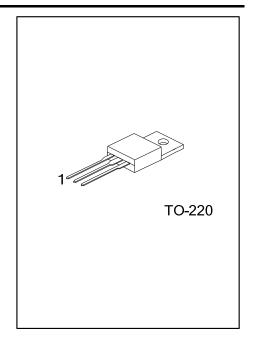
BTB24A Preliminary TRIAC

25A TRIACS

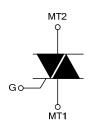
DESCRIPTION

The UTC **BTB24A** is a 25A triacs which can be operated in 3 quadrants only, it uses UTC's advanced technology to provide customers with high commutation performances and voltage insulated tab, etc.

The UTC **BTB24A** is suitable for inductive load switching operations, also can be used in ON/OFF function applications such as induction motor starting circuits, heating regulation, static relays etc.

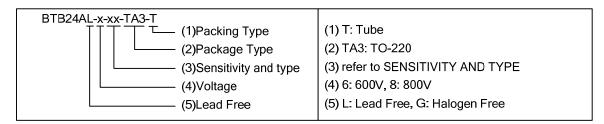


■ SYMBOL



■ ORDERING INFORMATION

| Ordering | Dookogo | Pin | Assignn | Dealine | | |
|--------------------|--------------------|--------|---------|---------|---------|------|
| Lead Free | Package | 1 | 2 | 3 | Packing | |
| BTB24AL-x-xx-TA3-T | BTB24AG-x-xx-TA3-T | TO-220 | MT1 | MT2 | G | Tube |

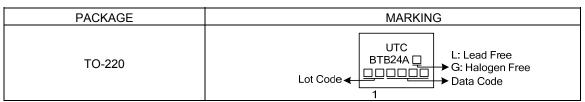


■ SENSITIVITY AND TYPE

| PART NUMBER VOLTAGE 600V | VOL | AGE | OENOITIV/ITY | TVDE | | |
|--------------------------|------|-------------|--------------|-------------|--|--|
| | 800V | SENSITIVITY | TYPE | | | |
| BW | 0 | 0 | 50mA | SNUBBERLESS | | |
| CW | 0 | 0 | 35mA | SNUBBERLESS | | |

⊚: Available

■ MARKING INFORMATION



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■ ABSOLUTE MAXIMUM RATINGS

| PARAMETER | | | SYMBOL | RATINGS | UNIT |
|----------------------------------------------------------------------------------------|----------------------|-----------------------|------------------------------------|-----------------------------------------|--------|
| RMS On-State Current (Full Sine Wave) T _C =75°C | | I _{T(RMS)} | 25 | Α | |
| Non Repetitive Surge Peak On-State Current (Full | F=50 Hz | t=20ms | I | 250 | Α |
| Cycle, T _J initial=25°C) | F=60 Hz | t=16.7ms | I _{TSM} | 260 | Α |
| I ² t Value for Fusing | t _P =10ms | | l ² t | 340 | A^2s |
| Critical Rate of Rise of On-State Current I _G =2xI _{GT} , tr≤100ns | F=120 Hz | T _J =125°C | dl/dt | 50 | A/μs |
| Non Repetitive Surge Peak Off-State Voltage | t _P =10ms | T _J =25°C | V _{DSM} /V _{RSM} | V _{DRM} /V _{RRM} +100 | V |
| Peak Gate Current | t _P =20µs | T _J =125°C | I_{GM} | 4 | Α |
| Average Gate Power Dissipation T _J =125°C | | $P_{G(AV)}$ | 1 | W | |
| Operating Junction Temperature | | T_J | -40~+125 | °C | |
| Storage Junction Temperature | | T _{STG} | -40~+150 | °C | |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL RESISTANCES

| PARAMETER | SYMBOL | RATINGS | UNIT |
|-----------------------|---------------|---------|------|
| Junction to Ambient | θ_{JA} | 60 | °C/W |
| Junction to Case (AC) | θ_{JC} | 0.8 | °C/W |

■ ELECTRICAL CHARACTERISTICS (T_J =25°C unless otherwise specified.)

| DADAMETED | SYMBOL TEST COND | | TIONS | | CW | | BW | | | UNIT |
|--------------------------------------------------------------------------|------------------|---------------------------------------------------------------------------|----------|-----|-----|-----|------|-----|-----|------|
| PARAMETER | STIVIBUL | TEST CONDITIONS | | MIN | TYP | MAX | MIN | TYP | MAX | UNIT |
| SNUBBERLESS TYPE (3 QUADRANTS) | | | | | | | | | | |
| Gate Trigger Current (Note 1) | I_{GT} | V _D =12V, | 1-11-111 | | | 35 | | | 50 | mA |
| Gate Trigger Voltage | V_{GT} | $R_L=33\Omega$ | 1-11-111 | | | 1.3 | | | 1.3 | V |
| Gate Non-Trigger Voltage | V_{GD} | $V_D=V_{DRM}$, $R_L=3.3k\Omega$, $T_J=125^{\circ}C$ | - - | 0.2 | | | 0.2 | | | V |
| Holding Current (Note 2) | l _Η | I _T =500mA | | | | 50 | | | 75 | mA |
| Latching Current | IL | I _G =1.2I _{GT} | 1-111 | | | 70 | | | 80 | mA |
| Latering Current | 'L | IG-1.ZIG | II | | | 80 | | | 100 | mA |
| Critical Rate of Rise of Off-State Voltage (Note 2) | dV/dt | V _D =67%V _{DRM} , Gate Open, T _J =125°C | | 500 | | | 1000 | | | V/µs |
| Critical Rate of Rise of Off-State Voltage at Commutation (Note 2) | (dl/dt)c | Without Snubber, T _J =125°C | | 13 | | | 22 | | | A/ms |

■ STATIC CHARACTERISTICS

| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|--------------------------------|------------------|---------------------------------------------|-----------------------|-----|-----|------|------|
| Peak On-State Voltage (Note 2) | V_{TM} | I _{TM} =35A, t _P =380μs | TJ=25°C | | | 1.55 | V |
| Threshold Voltage (Note 2) | V_{TO} | | T _J =125°C | | | 0.85 | V |
| Dynamic Resistance (Note 2) | R_D | | T _J =125°C | | | 16 | mΩ |
| Repetitive Peak Off-State | I _{DRM} | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | T _J =25°C | | | 5 | μΑ |
| Current | I _{RRM} | $V_{DRM}=V_{RRM}$ | TJ=125°C | | | 3 | mA |

Note: 1. Minimum I_{GT} is guaranteed at 5% of I_{GT} max.

2. For both polarities of MT2 referenced to MT1.

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